TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SG126FU

Bus Buffer with 3-STATE Output

Features

High-level output current: $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$

at $V_{CC} = 3.0 V$

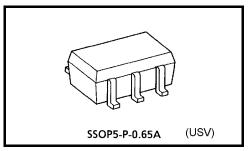
High-speed operation: $t_{pd} = 2.4 \text{ ns (typ.)}$

at $V_{CC} = 3.3 \text{ V}, 15 \text{pF}$

Operating voltage range: V_{CC} = 0.9~3.6 V

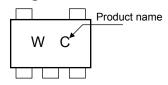
5.5-V tolerant inputs.

3.6-V power down protection output.

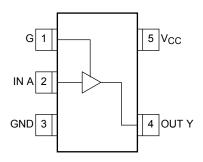


Weight: 0.006 g (typ.)

Marking



Pin Assignment (top view)



Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit
Power supply voltage	V _{CC}	-0.5~4.6	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	V	-0.5~ 4.6 (Note 1)	V
Input diode current	V _{OUT}	-0.5~ V _{CC} + 0.5 (Note 2)	V
Output diode current	I _{IK}	-20	mA
DC output current	lok	-20 (Note 3)	mA
DC V _{CC} /ground current	lout	±25	mA
Power dissipation	Icc	±50	mA
Storage temperature	PD	200	mW
Power supply voltage	T _{stg}	-65~150	°C

Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: $V_{CC} = 0V$

Note 2: High or Low State. IOUT abusolute maximum rating must be observed.

Note 3: VOUT < GND

IEC Logic Symbol

Truth Table



G	Α	Υ
L	Х	Z
Н	L	L
Н	Н	Н

Operating Ranges

Characteristics	Symbol	Value	Unit	
Power supply voltage	V_{CC}	0.9~3.6	V	
Input voltage	V _{IN}	0~5.5	V	
Output valtage	V	0~3.6 (Note 4)	V	
Output voltage	V _{OUT}	0~V _{CC} (Note 5)	\ \ \	
		±8.0 (Note 6)		
		±4.0 (Note 7)		
Output Current			1/1	±3.0 (Note 8)
Output Current	I _{OH} /I _{OL}	±1.7 (Note 9)	IIIA	
		±0.3 (Note 10)		
		±0.02 (Note 11)		
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dV	0~10 (Note 12)	ns/V	

Note 4: $V_{CC} = 0V$

Note 5: High or Low state.

Note 6: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 7: $V_{CC} = 2.3 \sim 2.7 \text{ V}$

Note 8: $V_{CC} = 1.65 \sim 1.95 \text{ V}$

Note 9: V_{CC} = 1.4~1.6 V

Note 10: $V_{CC} = 1.1 \sim 1.3 \text{ V}$

Note 11: $V_{CC} = 0.9 \text{ V}$

Note 12: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Tool	t Condition		-	Га = 25°C)	Ta = -4	0~85°C	Unit							
Characteristics		Syllibol	1691	Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Onit							
					0.9	V _C C	_	_	V _{CC}	_								
					1.1~1.3	V _{CC} × 0.7			V _{CC} × 0.7	_								
	High level	V _{IH}			1.4~1.6	V _{CC} × 0.65	_	_	V _{CC} × 0.65	_								
					1.65~ 1.95	V _{CC} × 0.65	_	_	V _{CC} × 0.65	_								
					2.3~2.7	1.7			1.7	_								
Input voltage					3.0~3.6	2.0			2.0	_	V							
input voltage					0.9	_	_	GND	_	GND	V							
					1.1~1.3	_	_	V _{CC} × 0.3	_	V _{CC} × 0.3								
	Low level	V _{IL}		_	1.4~1.6	_	_	V _{CC} × 0.35	_	V _{CC} × 0.35								
					1.65~ 1.95	_	_	V _{CC} × 0.35	_	V _{CC} × 0.35								
					2.3~2.7	_		0.7	_	0.7								
					3.0~3.6	_	_	0.8	_	0.8								
				I _{OH} =-0.02 mA	0.9	0.75	_	_	0.75	_								
		V _{ОН}		$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V _{CC} × 0.75	_	_	V _{CC} × 0.75	_								
	High level V _{Oh}		V _{OH}	V _{OH}	V _{OH}	V _{OH}	V _{OH}	V _{OH}	V _{OH}	V _{IN} = V _{IH}	$I_{OH} = -1.7 \text{ mA}$	1.4~1.6	V _{CC} × 0.75	_	_	V _{CC} × 0.75	_	
					VIH	$I_{OH} = -3.0 \text{ mA}$	1.65~ 1.95	V _{CC} -0.45			V _{CC} -0.45							
				$I_{OH} = -4.0 \text{ mA}$	2.3~2.7	2.0			2.0	_								
Output voltage				$I_{OH} = -8.0 \text{ mA}$	3.0~3.6	2.48	_	_	2.48	_	V							
Output Voltage				$I_{OL} = 0.02 \text{ mA}$	0.9	_	_	0.1	_	0.1	v							
				$I_{OL} = 0.3 \text{ mA}$	1.1~1.3	_		V _{CC} × 0.25	_	V _{CC} × 0.25								
	Low level	V _{OL}	V _{IN} = V _{IL}	I _{OL} = 1.7 mA	1.4~1.6	_		V _{CC} × 0.25	_	V _{CC} × 0.25								
			or VIH	I _{OL} = 3.0 mA	1.65~ 1.95	_		0.45	_	0.45								
				I _{OL} = 4.0 mA	2.3~2.7	_	_	0.4	_	0.4								
	lou		I _{OL} = 8.0 mA	3.0~3.6	_	_	0.4	_	0.4									
Input leakage current		I _{IN}	V _{IN} = 0~5	5.5V	0~3.6			±0.1		±1.0	μА							
3-state output off-s	tate current	l _{OZ}	V _{IN} = V _{IH} V _{OUT} = 0	or V _{IL} ~3.6V	0.9~3.6	_		1.0	_	10.0	μА							
Power off leakage	current	l _{OFF}	V _{IN} = 5.5° or V _{OUT} :	V = 3.6V	0.0	_	_	1.0	_	10.0	μА							
Quiescent supply of	current	Icc	$V_{IN} = V_{C0}$	_C or GND	3.6	_	_	1.0		10.0	μА							

AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Tost Condition	Test Condition		Га = 25°(Ta = -4	0~85°C	Unit
Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
			0.9	_	15.3	_	_	_	
			1.1~1.3	_	8.3	18.4	1.0	34.2	
		C _L = 10 pF,	1.4~1.6	_	5.0	8.5	1.0	10.0	
		$R_L = 1 M\Omega$	1.65~ 1.95	_	4.0	6.2	1.0	6.7	
			2.3~2.7	_	2.6	3.9	1.0	4.4	
			3.0~3.6	_	2.1	3.1	1.0	3.7	
			0.9		17.7	_	_	_	
			1.1~1.3		9.6	21.5	1.0	37.2	
Propagation delay time	t _{pLH}	C _L = 15 pF,	1.4~1.6		5.6	9.3	1.0	11.2	ns
i Topagation delay time	t_{pHL}	$R_L = 1 M\Omega$	1.65~ 1.95		4.5	6.9	1.0	7.1	113
			2.3~2.7		2.9	4.4	1.0	5.0	
			3.0~3.6		2.4	3.4	1.0	3.9	
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9		29.0	_	_	_	
			1.1~1.3	_	14.5	29.6	1.0	56.0	
			1.4~1.6	_	8.2	13.1	1.0	15.9	
			1.65~ 1.95	_	6.0	9.2	1.0	9.6	
			2.3~2.7	_	4.0	5.7	1.0	6.1	
			3.0~3.6	_	3.3	4.4	1.0	4.8	
		$C_L = 10 \text{ pF},$ $R_L = 100 \text{ k}\Omega$	0.9	_	22.7	_	_	_	
			1.1~1.3	_	10.9	18.7	1.0	29.8	
			1.4~1.6	_	5.9	8.7	1.0	9.8	
		$C_L = 10 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95		4.5	6.3	1.0	6.8	
			2.3~2.7	_	3.1	4.2	1.0	4.5	
			3.0~3.6	_	2.4	3.2	1.0	3.5	
		$C_L = 15 \text{ pF},$ $R_L = 100 \text{ k}\Omega$	0.9	l	25.3		_		
			1.1~1.3		11.9	20.7	1.0	34.7	
Output enable time	t _{pZL}		1.4~1.6	_	6.5	9.5	1.0	11.1	ns
	t _{pZH}	$C_L = 15 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95	_	4.9	6.8	1.0	7.2	
		_	2.3~2.7		3.3	4.4	1.0	4.8	
			3.0~3.6	_	2.5	3.4	1.0	3.7	
		$C_L = 30 \text{ pF},$ $R_L = 100 \text{ k}\Omega$	0.9	_	37.7	_	_		
			1.1~1.3	_	17.1	30.7	1.0	50.5	
			1.4~1.6	_	8.8	13.1	1.0	15.1	
		$C_L = 30 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95	_	6.6	9.2	1.0	9.9	
		_	2.3~2.7		4.1	5.4	1.0	5.8	
			3.0~3.6	_	3.1	4.1	1.0	4.5	

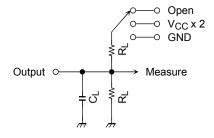
Characteristics	Symbol	Test Condition		-	Га = 25°C		Ta = -4	0~85°C	Unit							
Characteristics	Symbol	rest condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic							
		$C_L = 10 \text{ pF},$ $R_L = 100 \text{ k}\Omega$	0.9	_	117.6	_	_									
			1.1~1.3	_	9.2	16.0	1.0	22.4								
			1.4~1.6		7.1	9.1	1.0	10.4								
		$C_L = 10 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95		6.7	8.3	1.0	9.0								
			2.3~2.7		6.2	7.3	1.0	8.8								
			3.0~3.6		5.8	6.9	1.0	7.6								
	^t pLZ ^t pHZ	$\begin{aligned} C_L &= 15 \text{ pF}, \\ R_L &= 100 \text{ k}\Omega \end{aligned}$	0.9		139.2		_									
		$C_L = 15 \text{ pF},$ $R_L = 5 \text{ k}\Omega$ $C_L = 30 \text{ pF},$ $R_L = 100 \text{ k}\Omega$	1.1~1.3	_	10.0	16.9	1.0	25.1	ns							
Output disable time			1.4~1.6	_	7.8	9.8	1.0	11.3								
			$C_L = 15 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95	_	7.4	9.2	1.0	10.6							
											2.3~2.7		7.0	8.2	1.0	10.3
			3.0~3.6		6.8	7.7	1.0	9.5								
			0.9		230.8		_									
			1.1~1.3		14.0	20.8	1.0	31.9								
			1.4~1.6		12.2	13.5	1.0	14.9								
		$C_L = 30 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95		11.5	13.0	1.0	13.9								
			2.3~2.7		11.3	12.2	1.0	13.5								
			3.0~3.6	_	10.9	11.8	1.0	12.9								
Input capacitance	C _{IN}	_	3.6		3	-	_	_	pF							
Power dissipation capacitance	C _{PD}	(note13)	0.9 ~ 3.6	_	8	_	_	_	pF							

Note 13:C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC\ (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

AC Characteristics Measurement Circuit



Characteristics	Switch
t _{pLH} , t _{pHL}	Open
t_{pLZ}, t_{pZL}	V _{CC} x 2
t _{pHZ} , t _{pZH}	GND

 $Figure 1 \quad t_{pLH}, \, t_{pHL}$

AC Characteristics Measurement Circuit

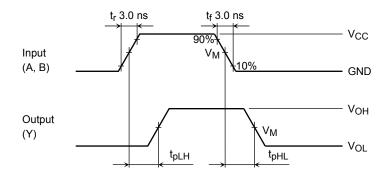


Figure 2 tpLH, tpHL

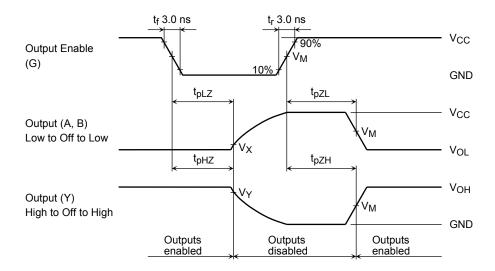


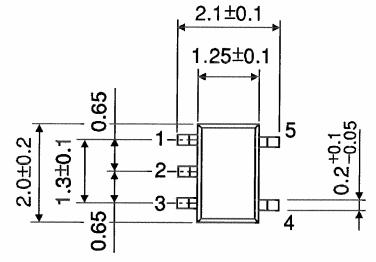
Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

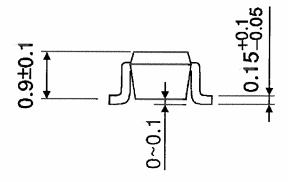
unit	Vcc								
dilit	3.3±0.3 V	2.5±0.2 V	1.8±0.15 V	1.5±0.1 V	1.2±0.1 V	0.9 V			
V_{M}	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2			
VX	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V	V _{OL} + 0.1 V	V _{OL} + 0.1 V	V _{OL} + 0.1 V			
VY	V _{OH} - 0.3 V	V _{OH} - 0.15 V	V _{OH} - 0.15 V	V _{OH} - 0.1 V	V _{OH} - 0.1 V	V _{OH} - 0.1 V			

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Package Dimensions

SSOP5-P-0.65A Unit: mm





Weight: 0.006 g (typ.)

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20070701-EN GENERAL

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